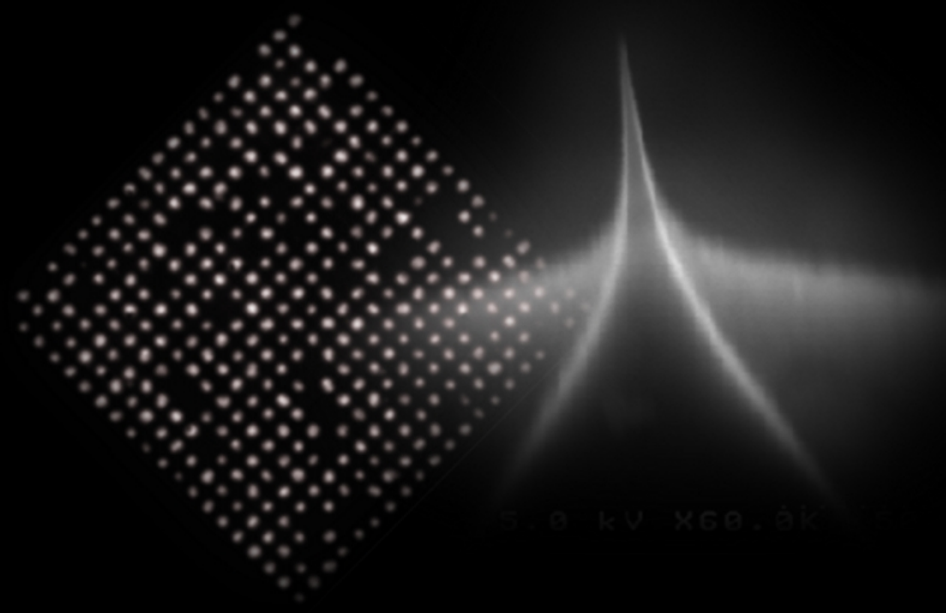




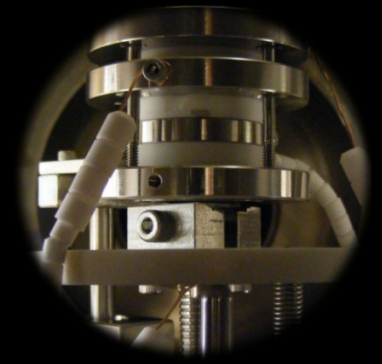
VANDERBILT UNIVERSITY

High-Brightness Field-Emission Cathodes for Accelerator Applications

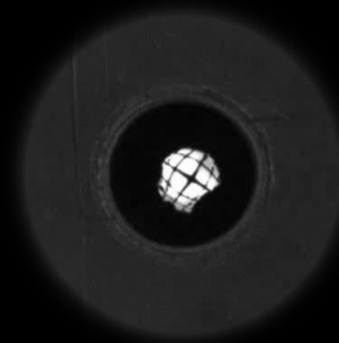
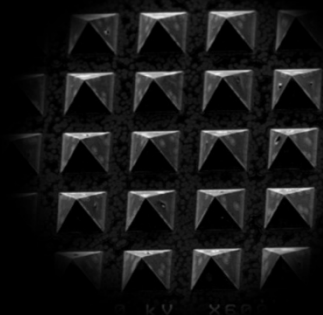


J. D. Jarvis, H. L. Andrews, C. A. Brau, & C. L. Stewart
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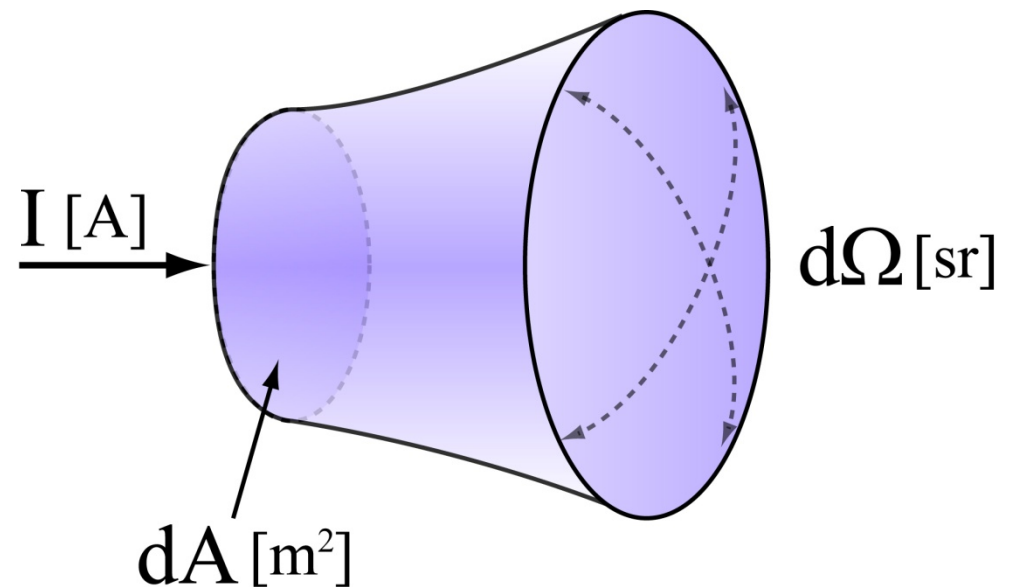
- **Brightness and Quantum Degeneracy**
- Diamond Field-Emitter Arrays
- Carbon-Nanotube Field-Emission Cathodes
- Conclusions



Normalized brightness describes the quality of an electron beam:

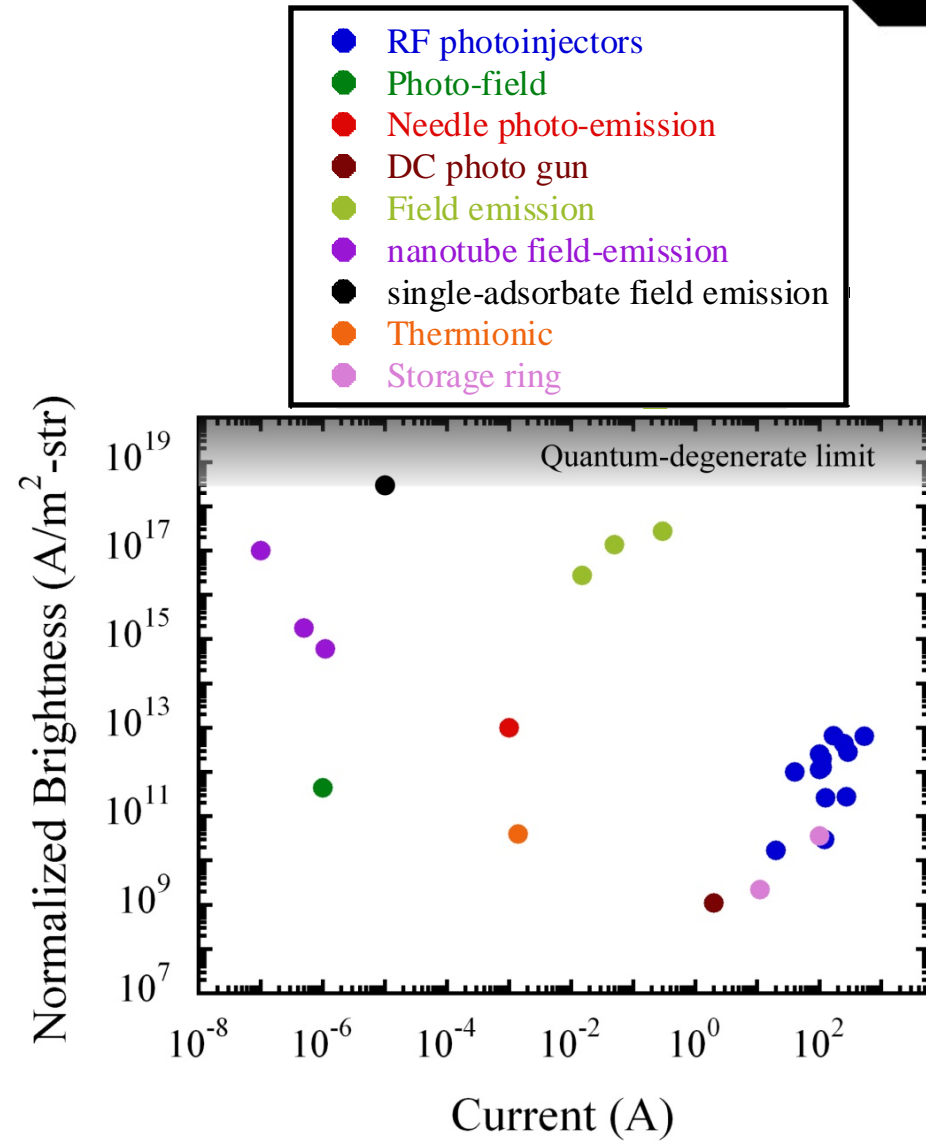
- Indicates how much current passes through a given area into a given angular extent
- The maximum achievable brightness is set by the electron source
- The 6-D brightness is the density of the beam ensemble in 6-D phase space

$$B_N = \frac{1}{\beta^2 \gamma^2} \frac{d^2 I}{dA d\Omega}$$



Electron source brightness spans nine orders of magnitude:

- Three primary emission mechanisms:
 - Thermionic emission
 - Photo emission
 - Field emission
- Field emission provides brightest beams but typically low current
- The brightness for certain field emitters approaches the universal limit set by QM effects

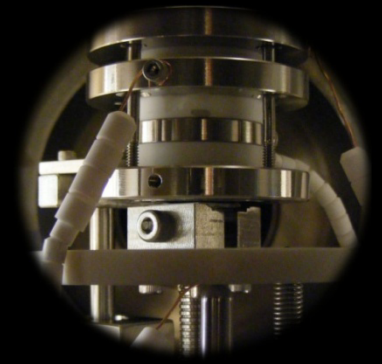


For a large 6-D brightness the anti-symmetry of electrons is important:

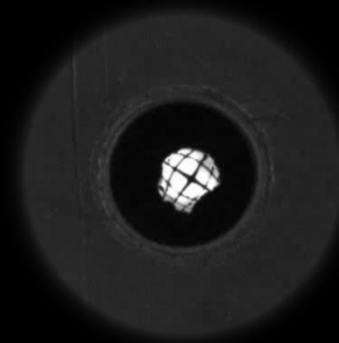
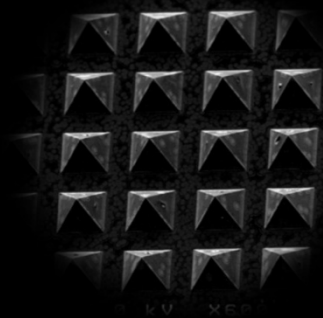
- The uncertainty principle and Pauli exclusion set a maximum phase-space number density of $2/h^3$ for fermions.
- A quantum-degenerate beam would have special properties such as suppressed e-e scattering (similar to electrons in a metal)
- Beams with high degeneracy should exhibit antibunching

$$\delta = \frac{h^3 d^6 N_e}{2 dx dp_x dy dp_y dE dt}$$



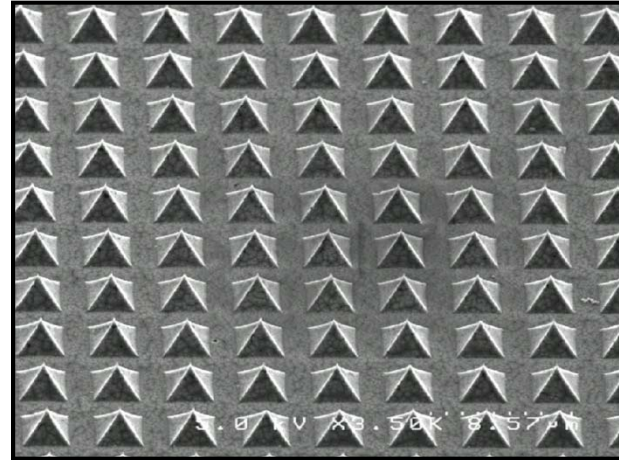


- Brightness and Quantum Degeneracy
- **Diamond Field-Emitter Arrays**
- Carbon-Nanotube Field-Emission Cathodes
- Conclusions

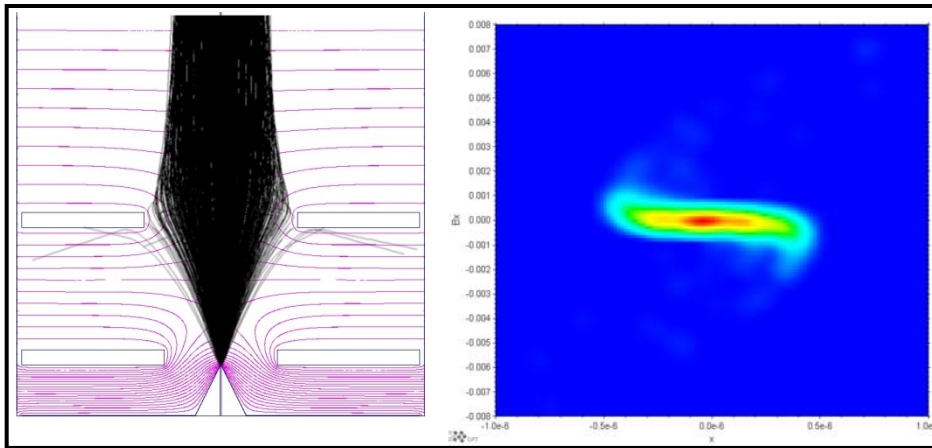


FEAs are microfabricated arrays of individual field emitters:

- Can be made with and without gate electrodes
- Emission can be time gated using various techniques
- Additional self-aligned electrodes may be included for beam collimation
- Many varieties, including Spindt type, CNT, Diamond (DFEA) etc..

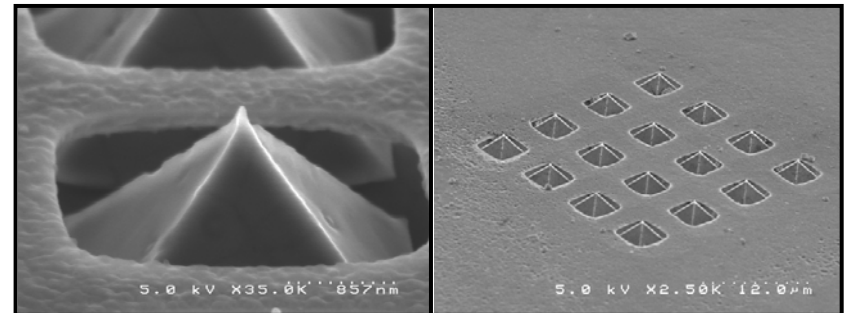


ungated DFEA



w/ collimation

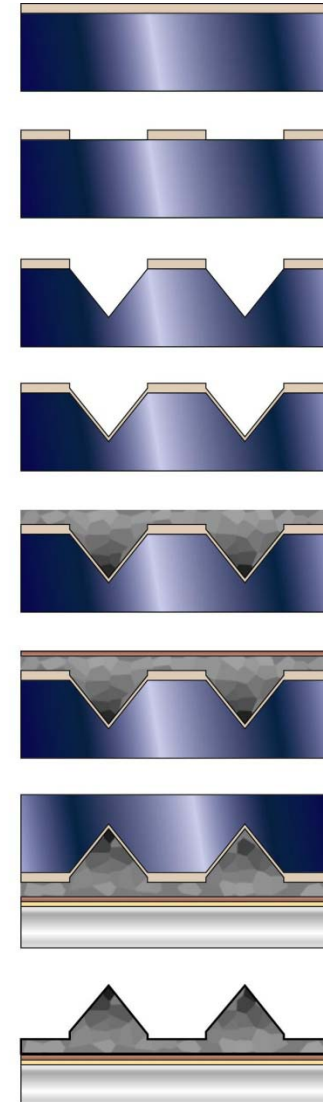
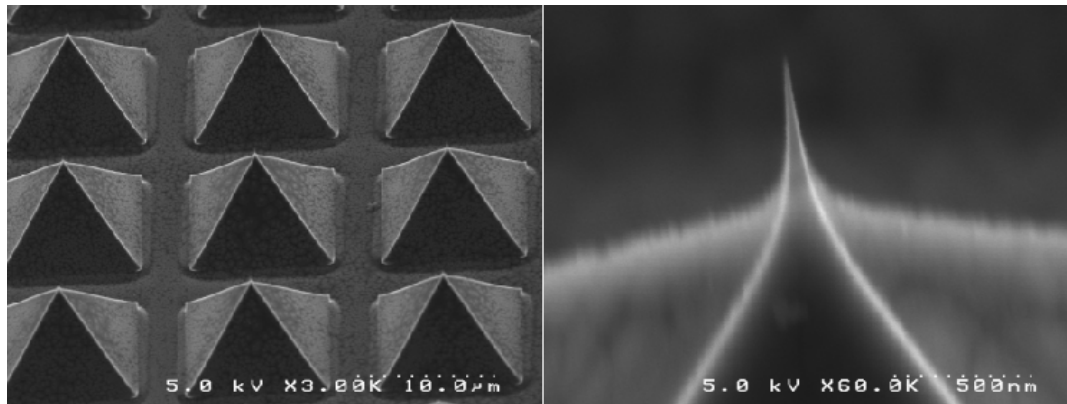
x-p_x phase space



Gated DFEA

Diamond field-emitter arrays are a promising new beam source:

- Developed at Vanderbilt by Davidson et al.
- Fabricated with an inverse mold transfer technique
- CVD diamond w/ boron and nitrogen
- Can be customized with multiple nanotips



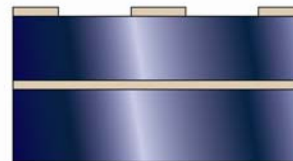
Gated DFEAs are now becoming operational:

- Gated DFEAs can be produced using either SOI or volcano processes
- Turn-on voltages of < 30 V (gate to cathode)
- Currently addressing issues with gate-oxide-surface contamination
- High-frequency response has not yet been measured or simulated
- Process flow for double-gated devices has yet to be determined

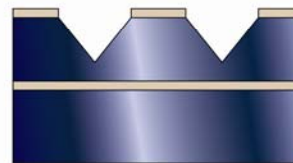
Dry oxidation of SOI @ 1100 C



Oxid patterning



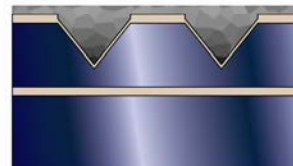
Anisotropic KOH etch @ 60 C



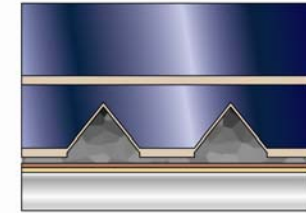
Tip mold sharpening: oxidation



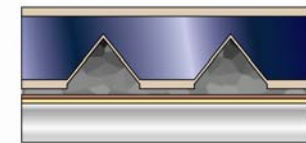
Diamond seeding and growth



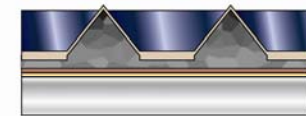
Metal deposition and brazing



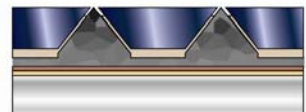
Handle Si removal



BOX removal and Si thinning

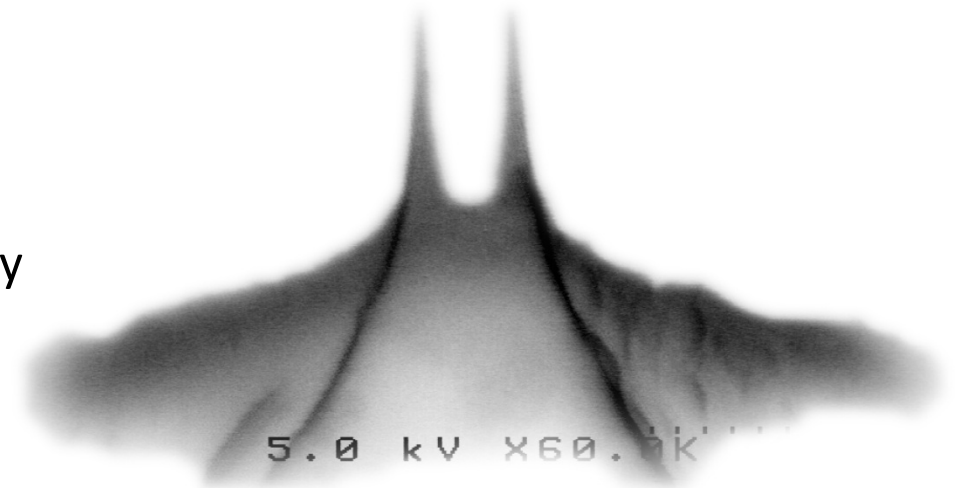


Exposed gate oxide removal



DFEAs have several advantages over photocathodes:

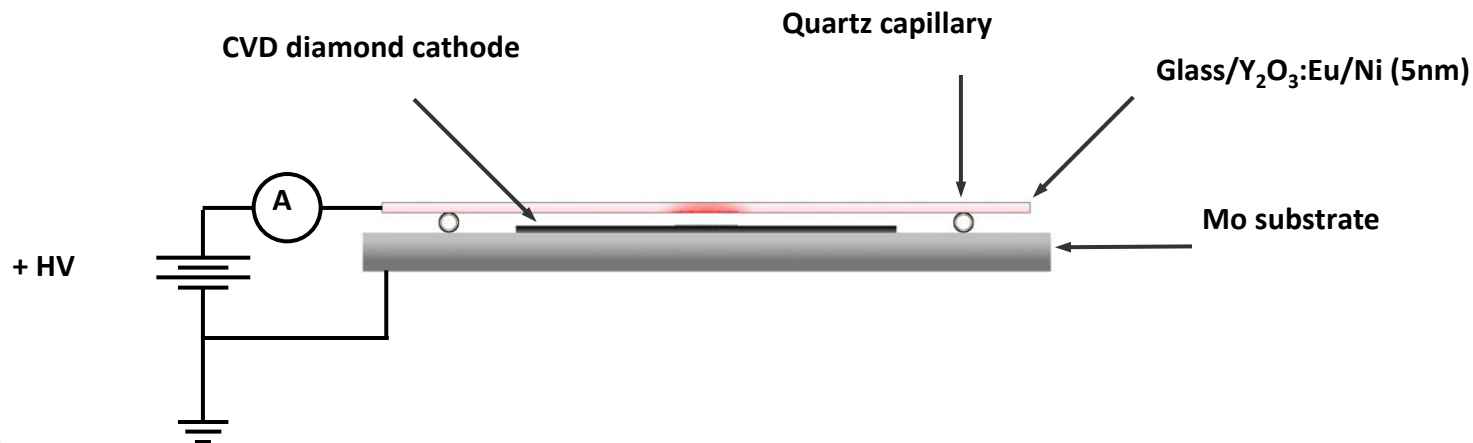
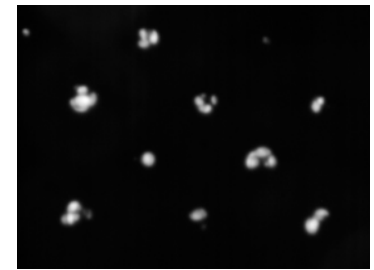
- Rugged: high thermal conductivity and chemically inert
- Tolerate poor vacuum operation, 10^{-5} Torr, transport in air
- Can be conditioned for highly uniform emission
- Degrade gracefully (ungated)
- No drive laser required
- Compatible with NCRF/SRF technology
 - No heat generated
 - No laser window required
- Photocathode survival in Ampere-class injectors is uncertain



DFEAs can be conditioned for highly uniform emission:

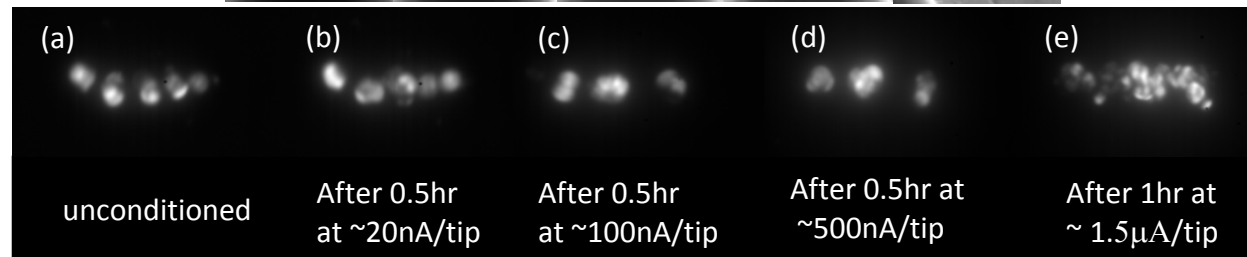
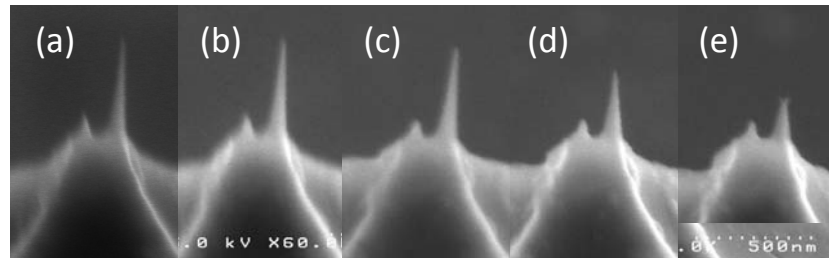
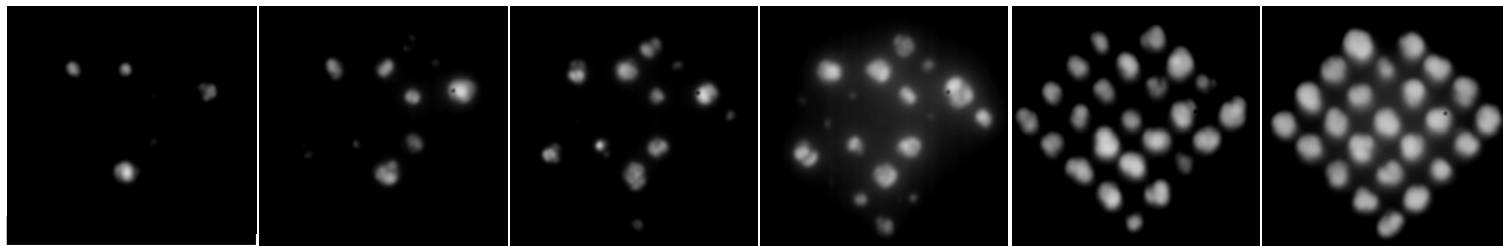
Investigated several conditioning methods:

1. Selective gas exposure
 - no improvement thus far
2. Thermal conditioning
 - High-field annealing of tightly adsorbed species
 - Greatly improved temporal stability
3. Moderate/high current operation
 - Morphology changes by thermal-assisted field evaporation



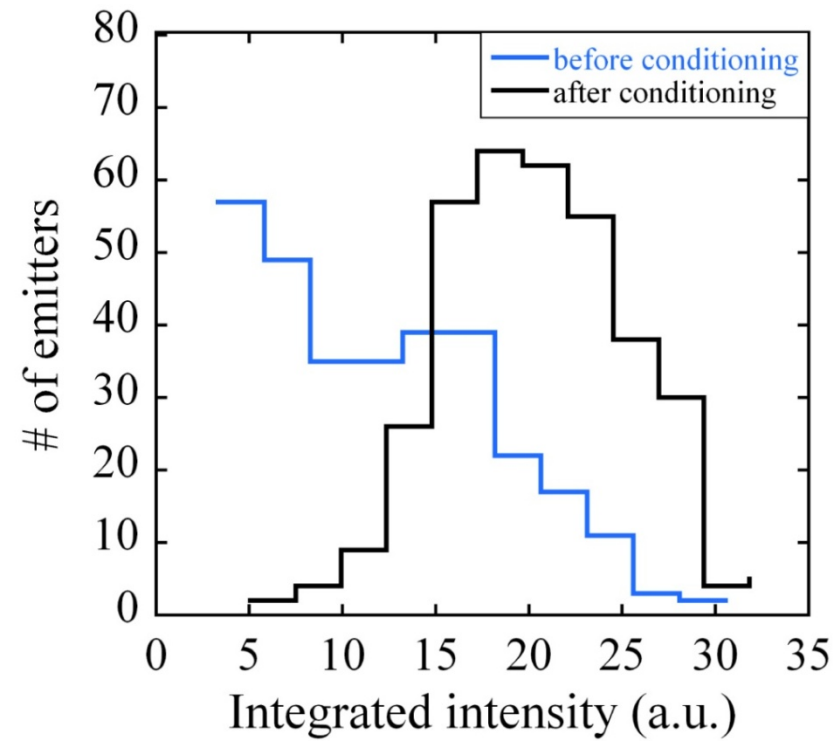
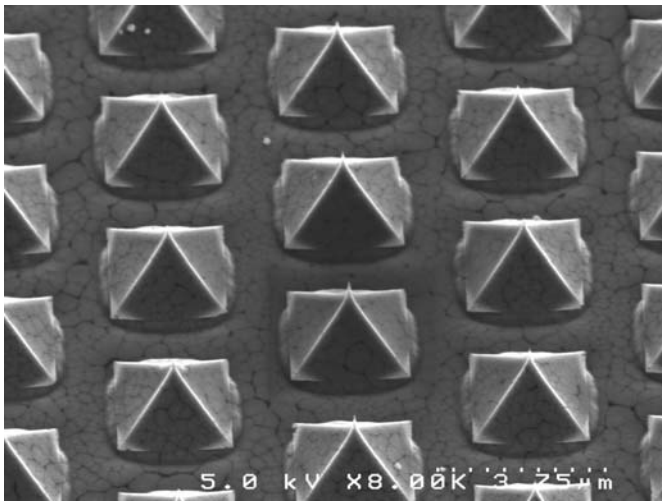
High-current conditioning is the most successful thus far:

- Evaporation of nanotips is self limiting, leading to highly uniform emission.
- Similar to pulsed conditioning of Spindt cathodes.
- DC Studies limited by anode destruction (maximum per-tip current thus far : 15 μA)



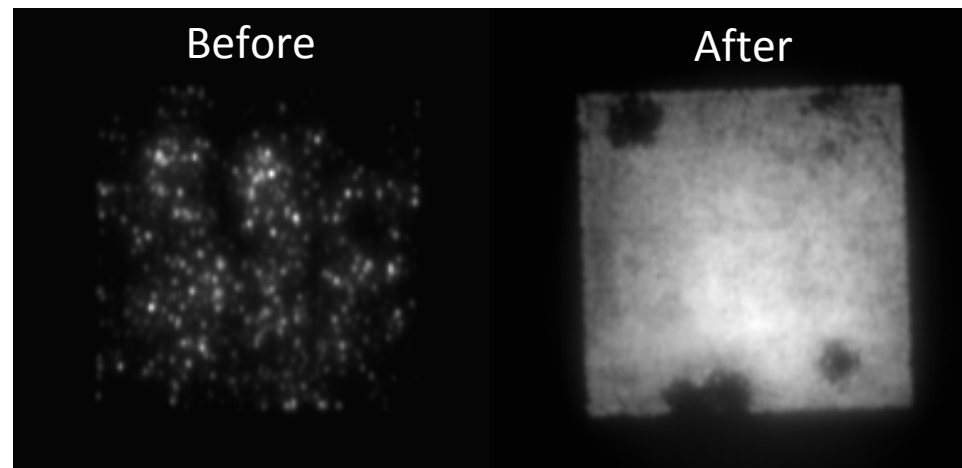
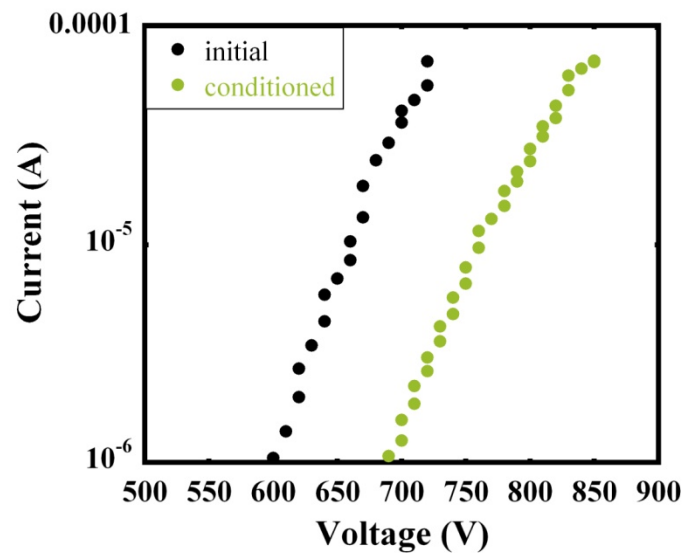
Close-diode DC conditioning is only possible for large-pitch arrays:

- Anode destruction prevents DC conditioning of dense arrays
- For 4 μm pitch array, 15 $\mu\text{A}/\text{tip}$, and 1.5 kV beam energy, the power density at anode is 100 kW/cm^2



Pulsed operation at microsecond time scales allows conditioning of dense arrays:

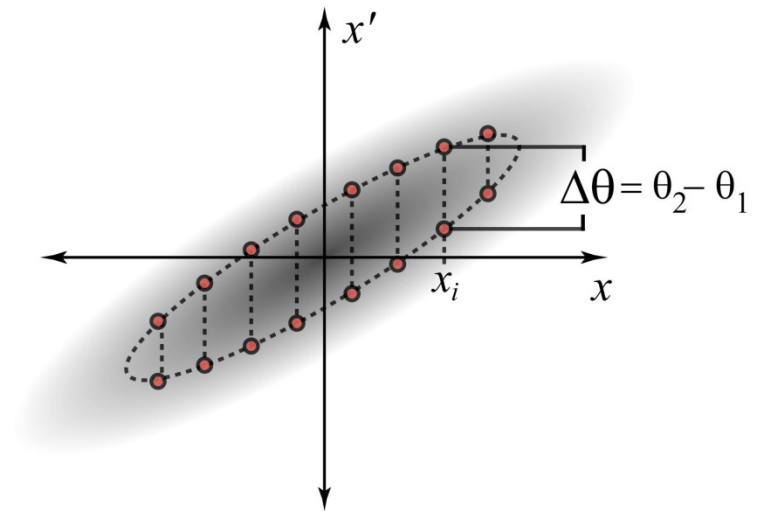
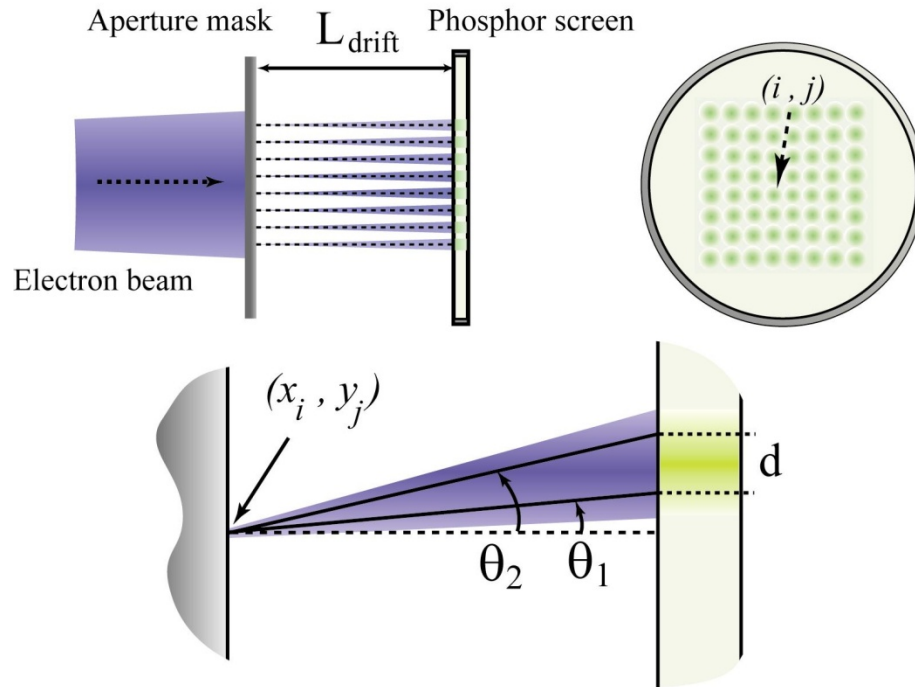
- Microsecond pulsing limits anode temperature rise to a few hundred °C



- Pulsed operation of a 4 μm pitch array recently achieved $\sim 30 \text{ A/cm}^2$ ($\sim 5 \mu\text{A}/\text{tip}$), limited by power supply.

The emittance can be measured with a pepperpot technique:

- Aperture array inserted into the beam samples the divergence for various transverse positions
- This allows the beam's "transverse trace space" to be determined



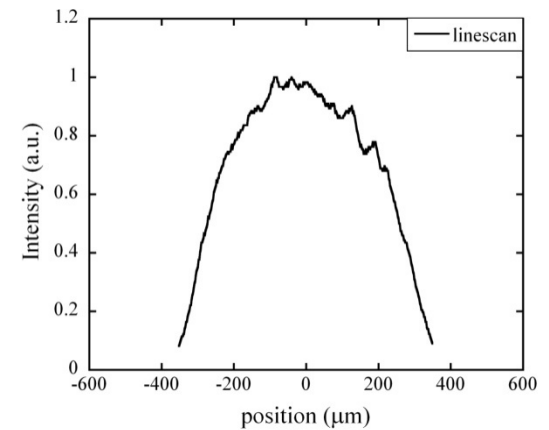
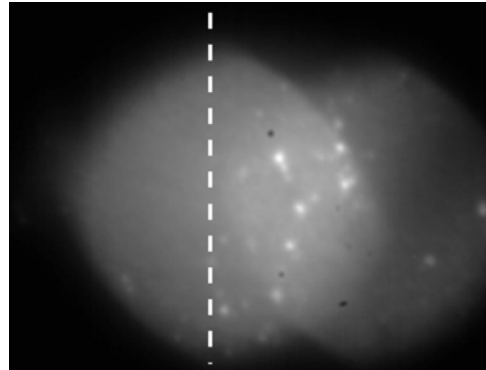
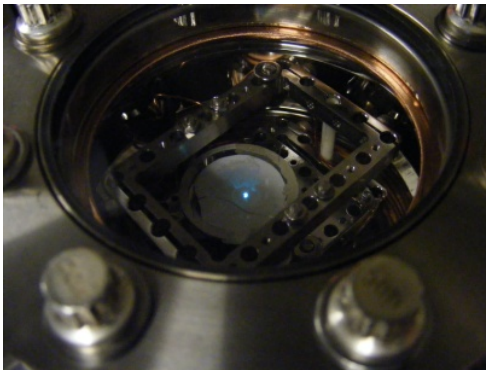
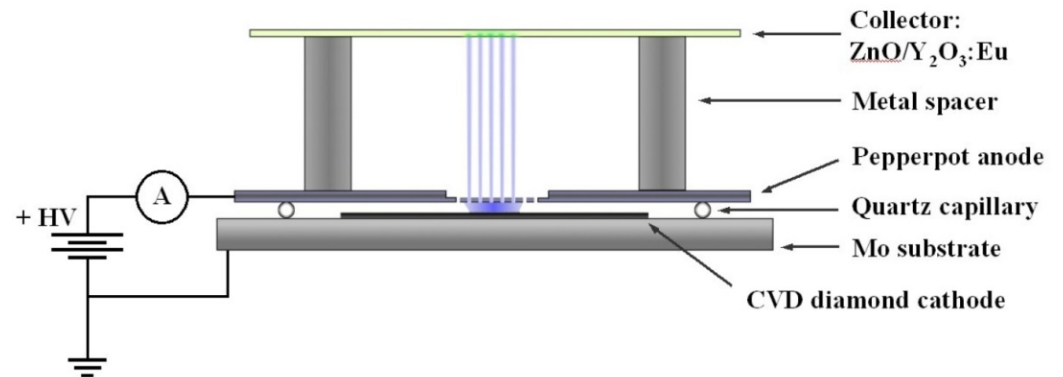
$$\epsilon_{N_x} = \beta\gamma\sigma_x\sigma_{x'}$$



Emittance for ungated arrays has been successfully measured:

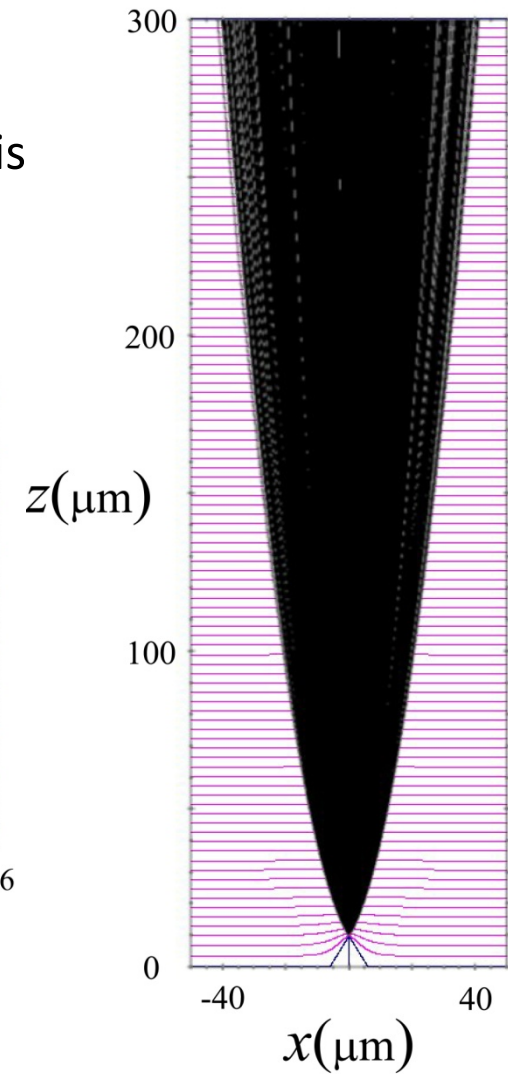
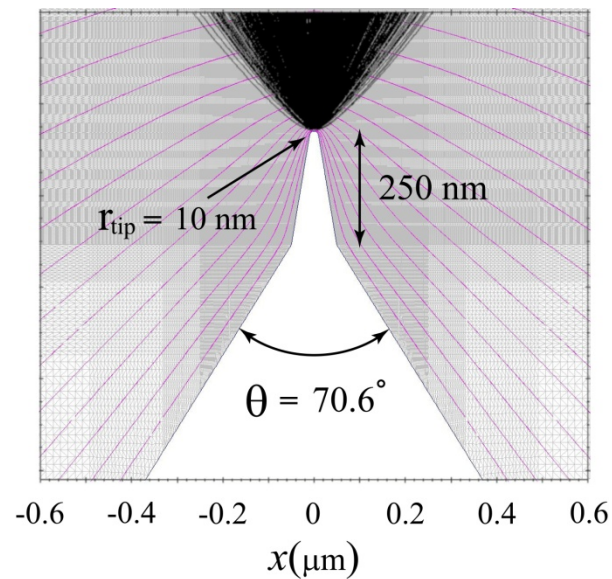
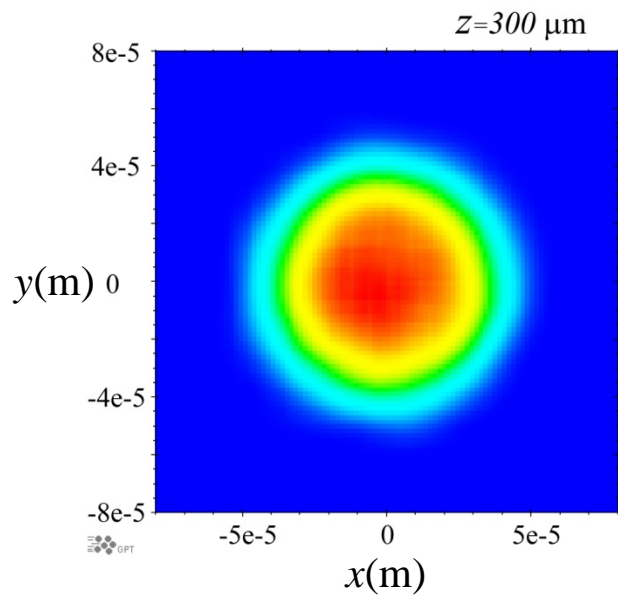
- For uniform emission, we may measure the expansion of a single beamlet
- Estimated rms divergence of ~ 38 mrad
- For 2 kV beam and a 1 mm cathode, normalized x-emittance is:

$$\epsilon_{N_x} \approx 1 \text{ mm-mrad}$$



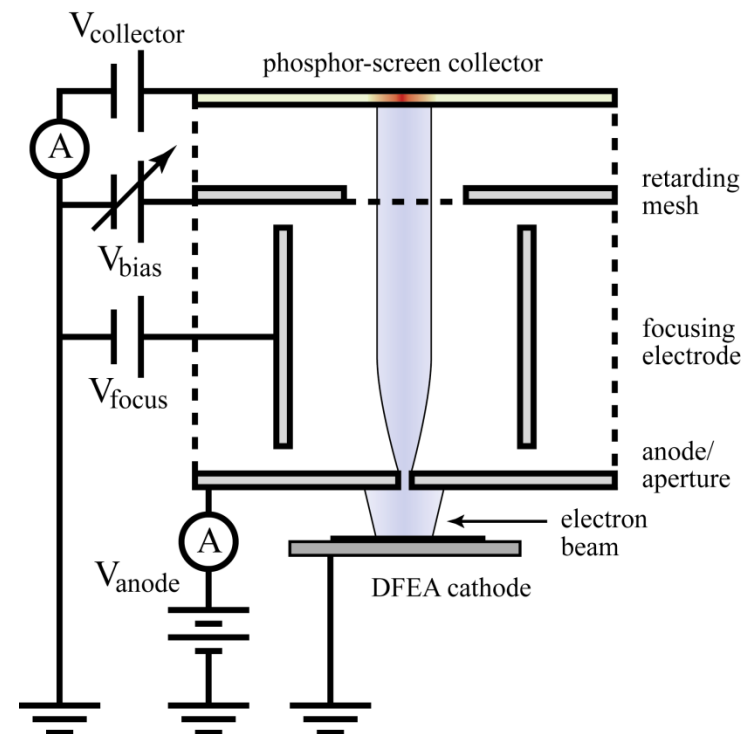
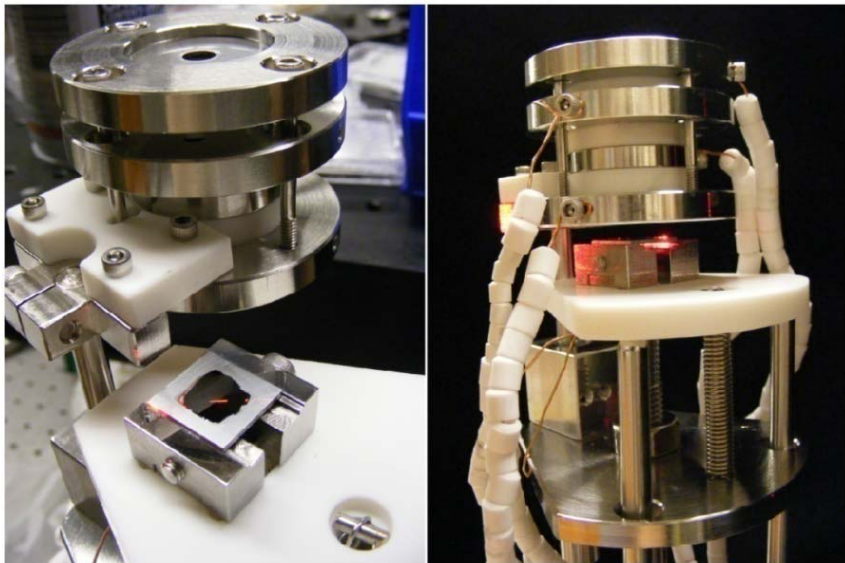
Simulated single tip divergence agrees well with experiment:

- Simulations performed in POISSON/GPT
- For the same conditions, the simulated rms divergence is ~ 40 mrad



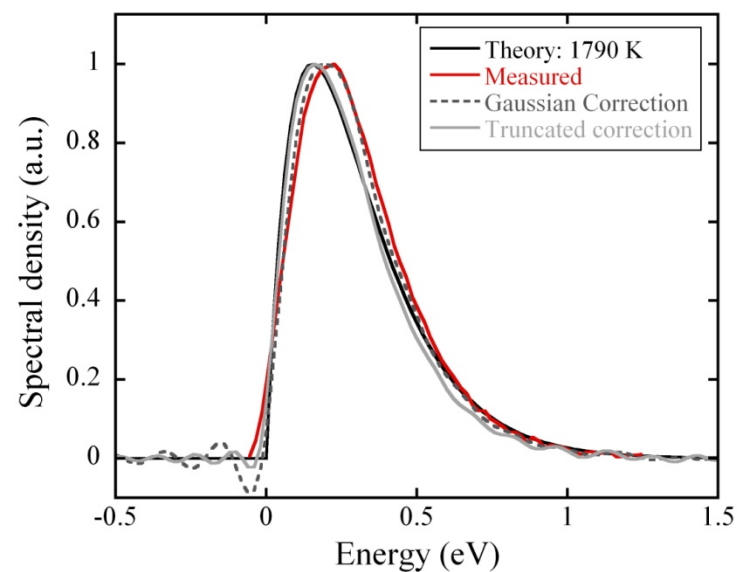
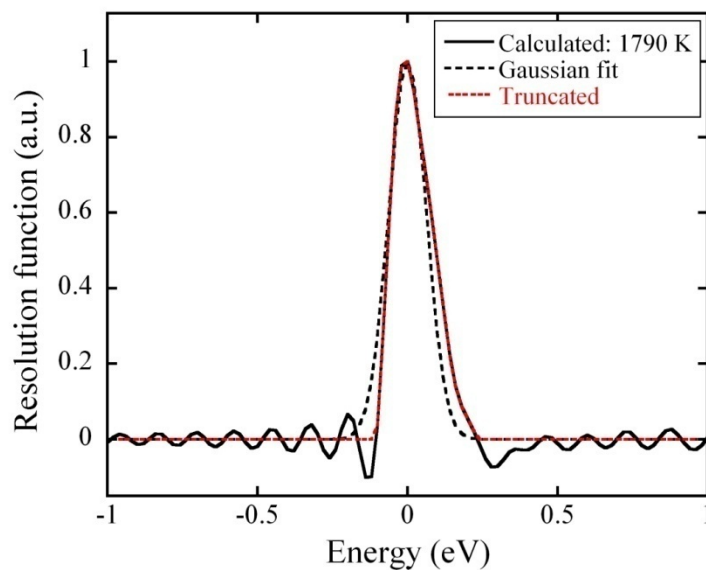
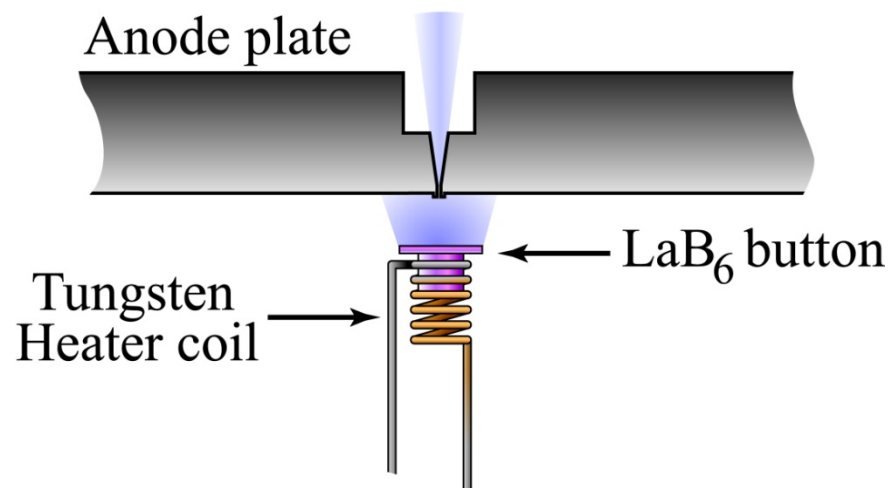
High-resolution energy analyzer built for examining spectrum from DFEAs:

- Based on University of Maryland (UMER) design
- Focusing electrode improves resolution by several orders of magnitude
- Integrated into DC teststand capable of anode-cathode planarity and gap adjustment during high-voltage operation



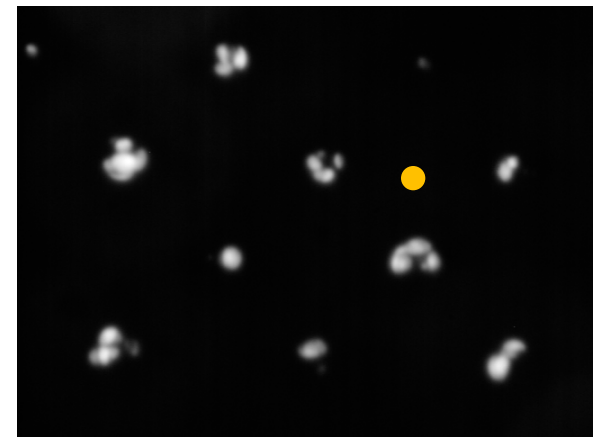
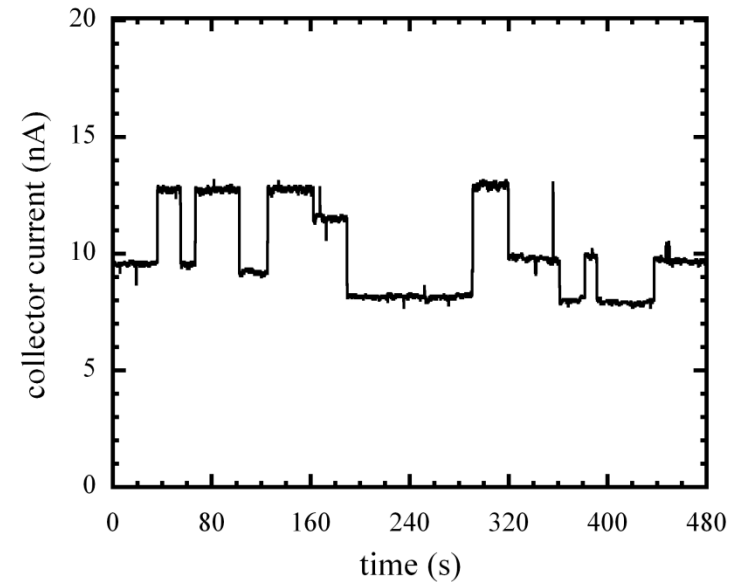
Instrumental broadening by analyzer was determined with a thermionic source:

- Known thermionic distribution is used to extract the analyzer's resolution function; FWHM = 0.15 eV
- Measured distribution agrees well with theory
- DFEA spectra can be measured with confidence

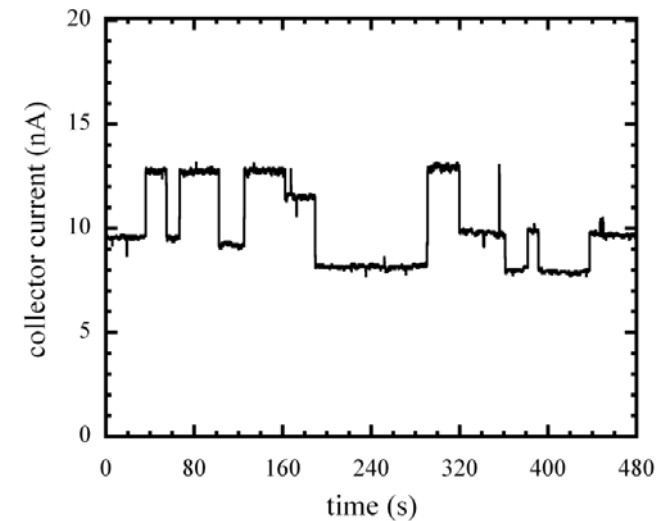
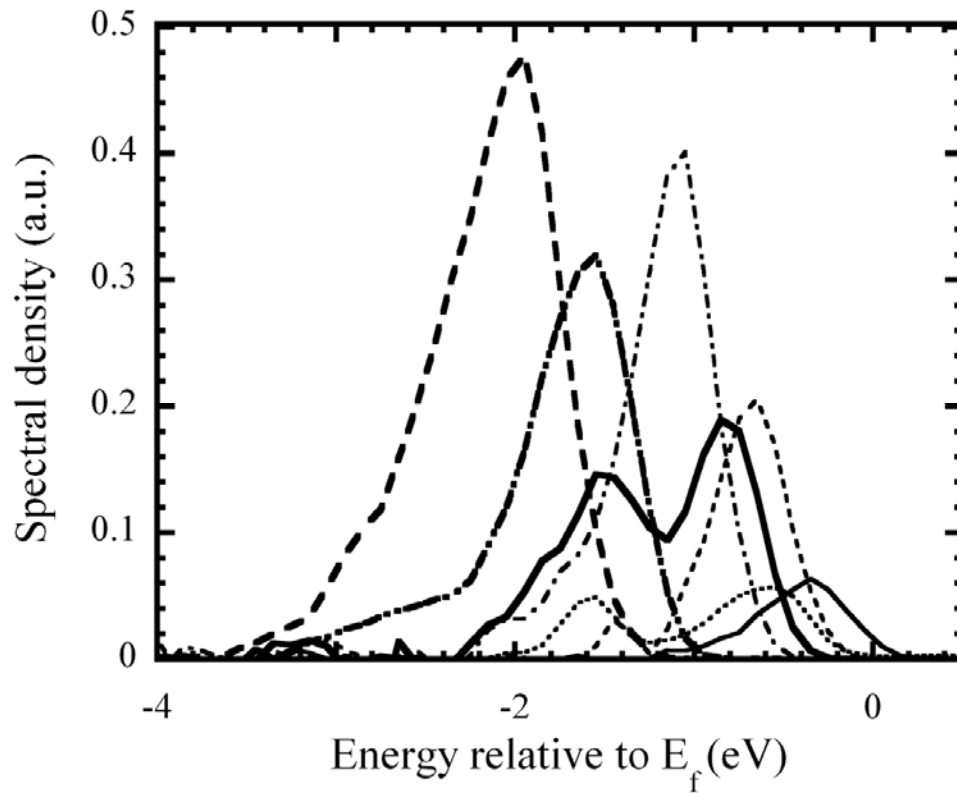


From previous experiments, emission is expected to be adsorbate dominated:

- Adsorbates are known to modify the intensity and spectrum of field-emission
- Resonant tunneling effects greatly enhance the tunneling probability at certain energies
- Typically, adsorbates remain stable for many seconds (long enough to acquire spectra)
- Analyzer aperture examines current from a single tip at a time



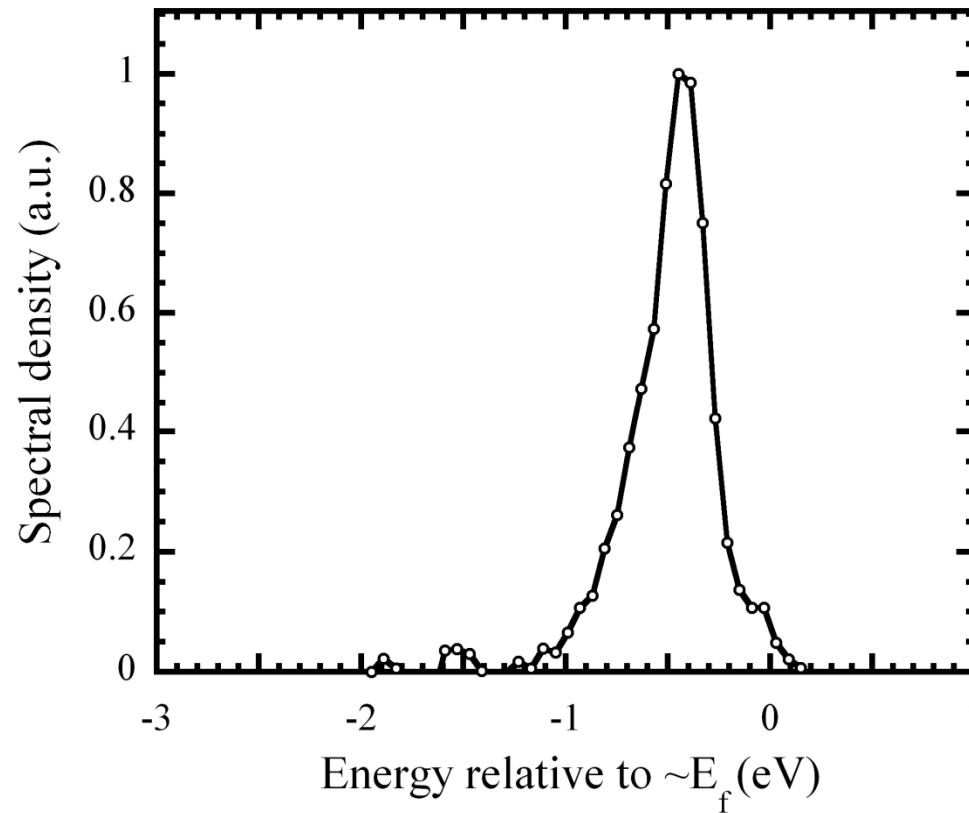
Adsorbates significantly modify the energy spectrum of a clean emitter:



- Each spectrum taken for identical experimental conditions during various periods of stable emission
- Transitions between spectra are concurrent with emission current fluctuations



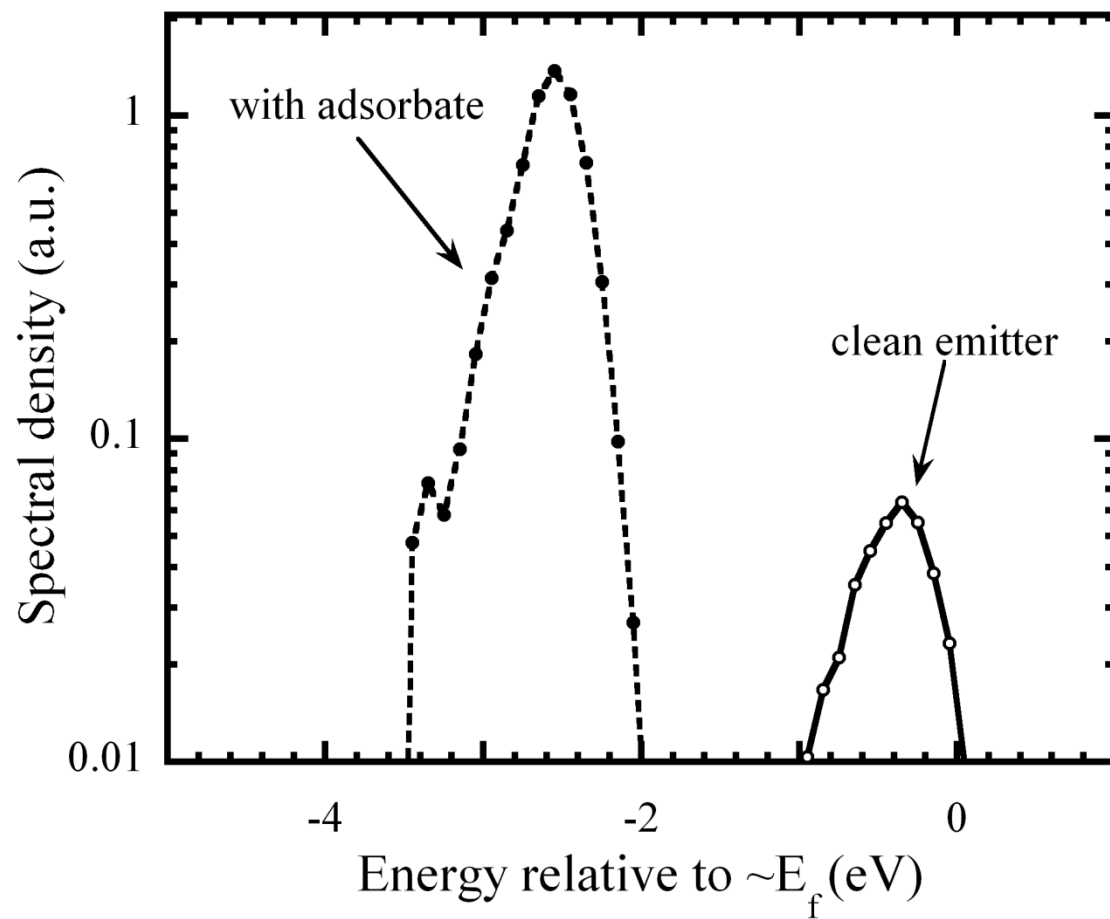
Spectrum from a clean emitter (purported) is similar to that of metals:



- Expect “clean” spectra to occur at low intensity and near the Fermi energy
- FWHM of ~ 0.3 eV, narrowest spectrum observed
- The effects of varying sp^2 , sp^3 , boron, and nitrogen unknown

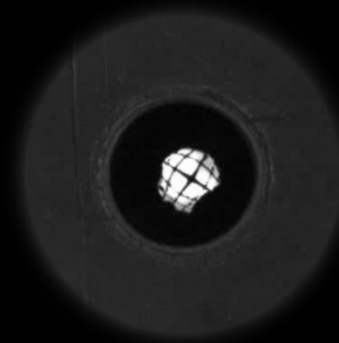
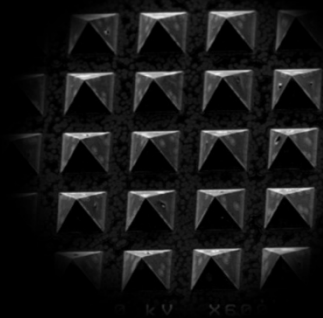


Observe order-of-magnitude current enhancements without spectral broadening:



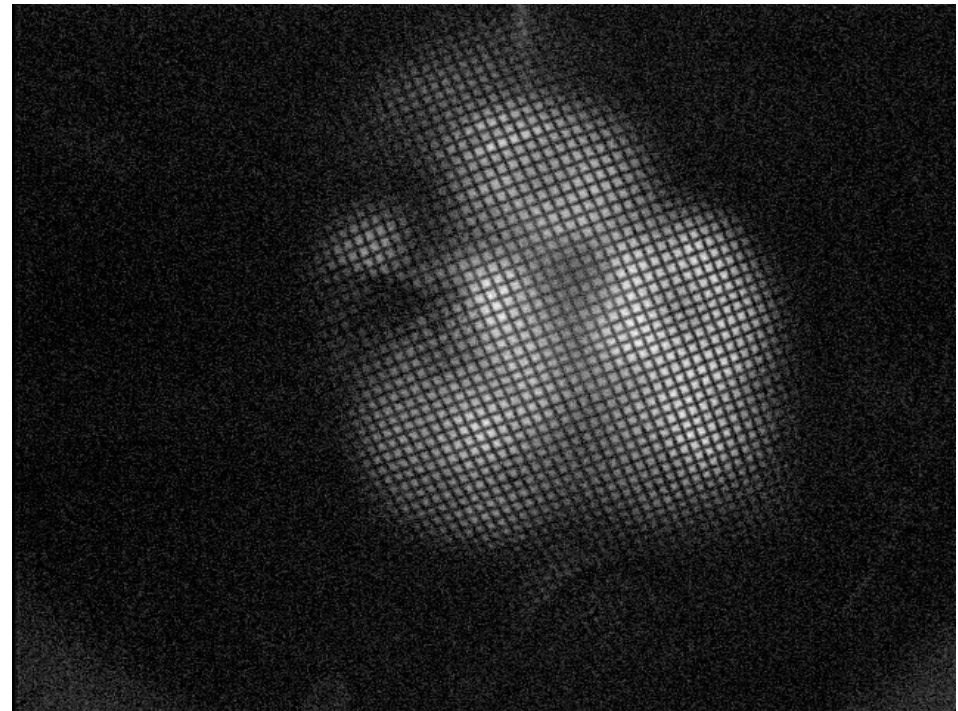
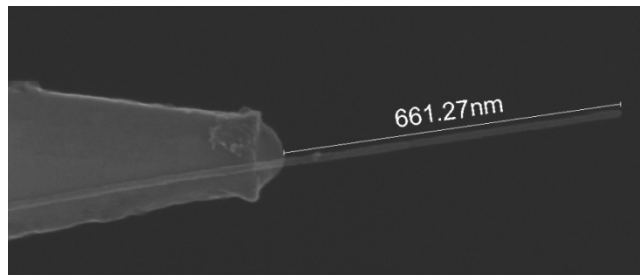
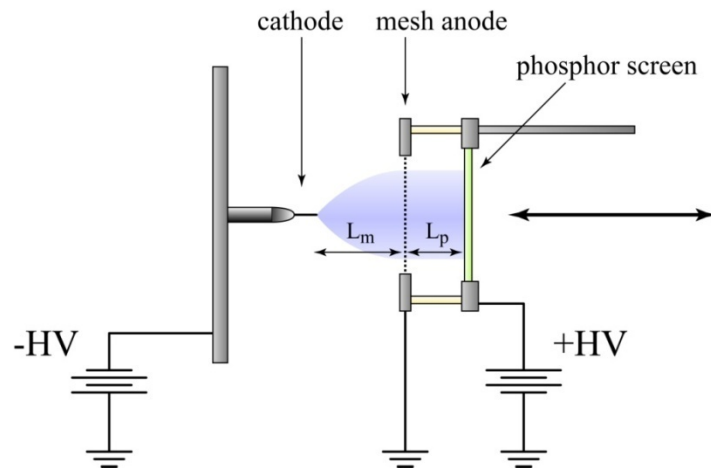


- Brightness and Quantum Degeneracy
- Diamond Field-Emitter Arrays
- **Carbon-Nanotube Field-Emission Cathodes**
- Conclusions



A field-emission microscope was built for studying CNT field emission:

- Large fields at the emitter surface “freeze” in an image of the emission area

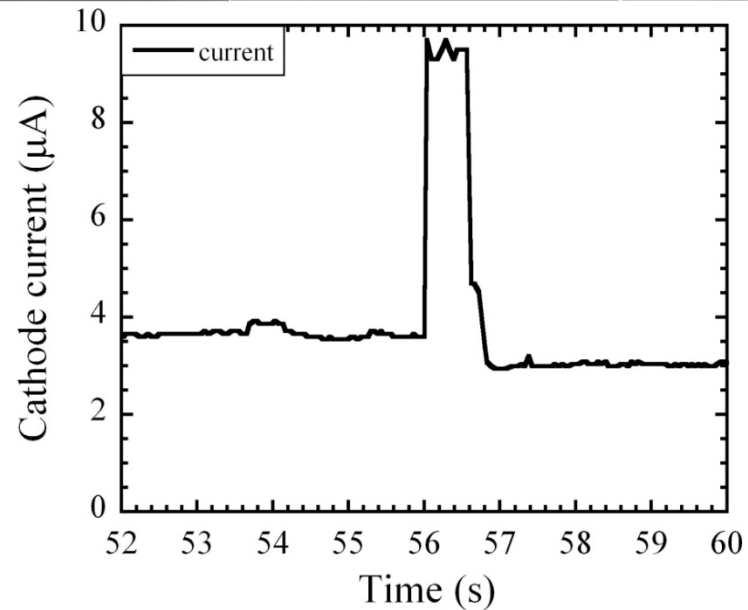
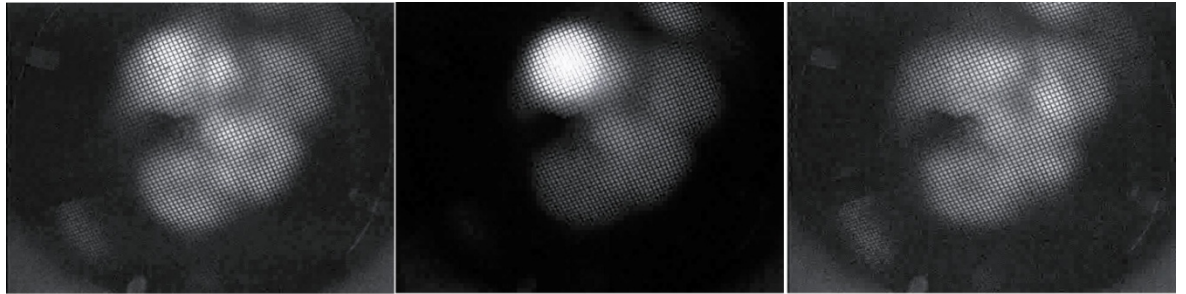


- Pentagonal rings, indicative of a clean nanotube cap, are clearly visible
- Adsorbate migration and large, localized current enhancements are seen



An adsorbate on a carbon nanotube field emitter may produce a QDEB:

- A single adsorbate more than doubled the total emitted current (+6 μA)
- Transient event, only lasting a fraction of a second
- If the adsorbate is presumed to be a single, small molecule, then the brightness is estimated to be quantum degenerate (assuming $dE \sim 0.3 \text{ eV}$)



“Designer” metal adsorbates on CNTs may provide stable QDEB sources:

- Binding energies for residual gases on CNTs are typically fractions of an eV, even with induced polarization from field gradient at tip
- DFT calculations demonstrate a range of different zero-field binding energies for metals atoms on CNTs
- The goal is to locate a metal adsorbate that significantly enhances local emission, and is stable at the currents required for high degeneracy
- Because of the close parallels between CNTs and DFEA tips, these specialized adsorbates might also be used to enhance DFEA emission properties



Conclusions:

- There is a quantum-degenerate limit to electron beam brightness
- DFEAs can tolerate poor operating conditions, be conditioned for highly uniform emission, be produced in an arbitrary footprint
- While gated arrays are now becoming operational, ungated arrays have demonstrated 30 A/cm^2 in μs -pulsed operation and should easily scale past the 100 A/cm^2 mark. Much higher per-tip currents might be achievable in ps pulses.
- DFEAs are slated for testing in several RF guns (ANL, NPS, LANL)
- The importance of adsorbed species in field emission from DFEA tips has been established
- The use of specialized metal adsorbates on CNTs may provide a $10 \mu\text{A}$ level QDEB source
- DFEA performance might be improved in the same manner

